

Power Transistor (80V, 7A)

2SD2611

●Features

- 1) Low saturation voltage, typically $V_{CE(sat)} = 0.3V$ at $I_C / I_B = 4 / 0.4A$.
- 2) Excellent DC current gain characteristics.
- 3) $P_c = 30W$ ($T_c = 25^\circ C$)
- 4) Wide SOA (safe operating area).
- 5) Complements the 2SB1672.

●Absolute maximum ratings ($T_a = 25^\circ C$)

| Parameter | Symbol | Limits | Unit |
|-----------------------------|-----------|------------|----------------------------|
| Collector-base voltage | V_{CBO} | 100 | V |
| Collector-emitter voltage | V_{CEO} | 80 | V |
| Emitter-base voltage | V_{EBO} | 5 | V |
| Collector current | I_C | 7 10 | A(DC) A(Pulse) * |
| Collector power dissipation | P_c | 2 30 | W W($T_c=25^\circ C$) |
| Junction temperature | T_j | 150 | $^\circ C$ |
| Storage temperature | T_{stg} | -55 ~ +150 | $^\circ C$ |

* Single pulse, $P_w=100ms$

●Packaging specifications and h_{FE}

| Type | 2SD2611 |
|------------------------------|----------|
| Package | TO-220FN |
| h_{FE} | DEF |
| Code | - |
| Basic ordering unit (pieces) | 500 |

●Electrical characteristics ($T_a = 25^\circ C$)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|--------------------------------------|---------------|------|------|------|---------|--|
| Collector-base breakdown voltage | BV_{CBO} | 100 | - | - | V | $I_C = 50\mu A$ |
| Collector-emitter breakdown voltage | BV_{CEO} | 80 | - | - | V | $I_C = 1mA$ |
| Emitter-base breakdown voltage | BV_{EBO} | 5 | - | - | V | $I_E = 50\mu A$ |
| Collector cutoff current | I_{CBO} | - | - | 10 | μA | $V_{CB} = 100V$ |
| Emitter cutoff current | I_{EBO} | - | - | 10 | μA | $V_{EB} = 4V$ |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | - | - | 1 | V | $I_C/I_B = 4A/0.4A$ * |
| Base-emitter saturation voltage | $V_{BE(sat)}$ | - | - | 1.5 | V | $I_C/I_B = 4A/0.4A$ * |
| DC current transfer ratio | h_{FE} | 60 | - | 320 | - | $V_{CE} = 5V$, $I_C = 1A$ * |
| Transition frequency | f_T | - | 5 | - | MHz | $V_{CE} = 5V$, $I_E = -0.5A$, $f = 5MHz$ * |
| Output capacitance | C_{ob} | - | 150 | - | pF | $V_{CB} = 10V$, $I_E = 0A$, $f = 1MHz$ |

* Measured using pulse current